

SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

MCH6001 — NPN Epitaxial Planar Silicon Composite Transistor **High Frequency Low-Noise Amplifier**

Features

- Low-noise use : NF=1.2dB typ (f=1GHz)
- High cut-off frequency : $f_T=16GHz$ typ (VCE=5V)
- High gain : $|S21e|^2 = 16dB$ typ (f=1GHz)
- · Composite type with 2 RF transistor MCH4020 in one package facilitating high-density mounting

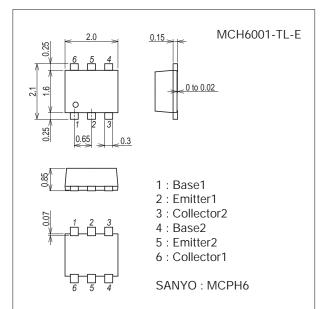
Specifications

Absolute Maximum Ratings at Ta=25°C

•				
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		15	V
Collector-to-Emitter Voltage	VCEO		8	V
Emitter-to-Base Voltage	VEBO		2	V
Collector Current	IC		150	mA
Collector Dissipation	PC	When mounted on glass epoxy substrate 1unit	400	mW
Total Dissipation	PT	When mounted on glass epoxy substrate	600	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Package Dimensions

unit : mm (typ) 7022A-019



Product & Package Information

 Package : MCPH6

• JEITA, JEDEC

: SC-88, SC-70-6, SOT-363

• Minimum Packing Quantity : 3,000 pcs./reel

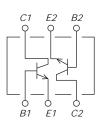
Packing Type : TL

\bigcirc 0



Marking

Electrical Connection



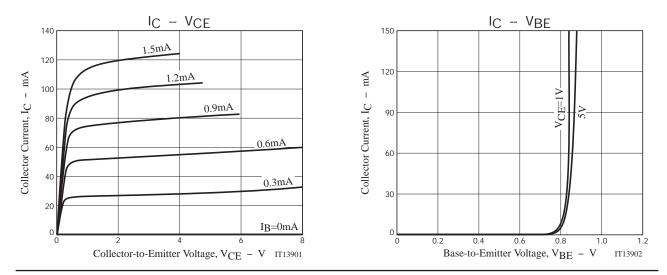
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
	Symbol	Conditions	min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =5V, I _E =0A			1.0	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =1V, I _C =0A			1.0	μΑ
DC Current Gain	hFE	V _{CE} =5V, I _C =50mA	60		150	
Gain-Bandwidth Product	fT	V _{CE} =5V, I _C =50mA	13	16		GHz
Forward Transfer Gain	S21e ²	VCE=5V, IC=50mA, f=1GHz		16		dB
Noise Figure	NF	V _{CE} =1V, I _C =10mA, f=1GHz		1.2	1.8	dB

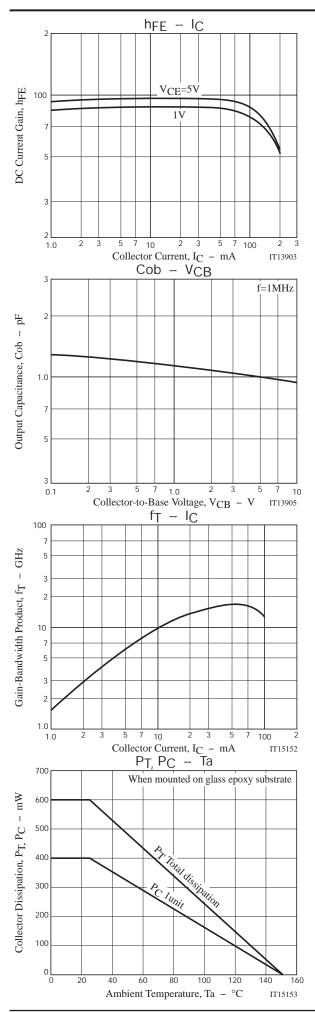
Note) Pay attention to handling since it is liable to be affected by static electricity due to the high-frequency process adopted.

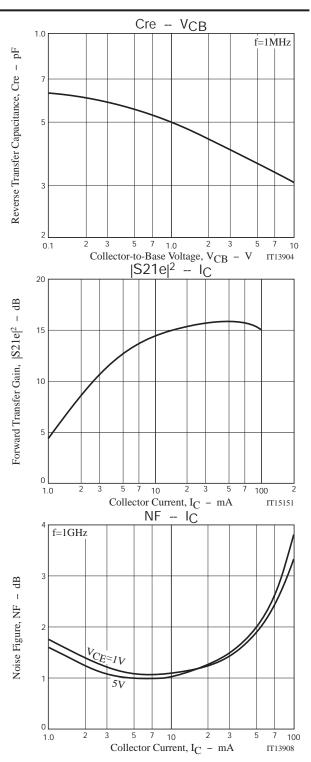
Ordering Information

Device Package		Shipping	memo	
MCH6001-TL-E	MCPH6	3,000pcs./reel	Pb Free	



MCH6001





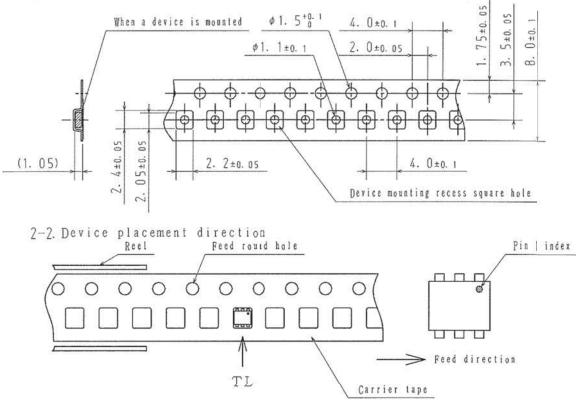
Embossed Taping Specification MCH6001-TL-E

1. Packing Format

MCPH6 Packing metho	Type MCP4	Reel 3, 000	[aner box 15, 000	Outer box 90,000	Inner BOX (C- 5 reels contained Dimensions:mm (exte	6 inner boxes conlained
		3, 000	15, 000	90, 000		
Packing metho		- 			D.m	rnal) [] Dimensions:mm (external)
Packing metho	n d				183×72×18	5 440×195×210
A			<u>Reel</u>	(u r	nit:mm)	<u>Juter box label</u> [t is a label at the time of factory shipmer The form of a label may change in plysical distribution process. 1 108
	LOT I Quan	No.				TYPE CODE
	Orig	in		* Z) 7 2 2 0 \$\$\$MBL?:**** (PACKAGE
	Reel la	b e l	Th	e LEAD FR	REE X description sho of the terminal is le	ws that the surface ad free.
				Label		
				LEAD FRE	CE 3 JEITA Phase	3.4

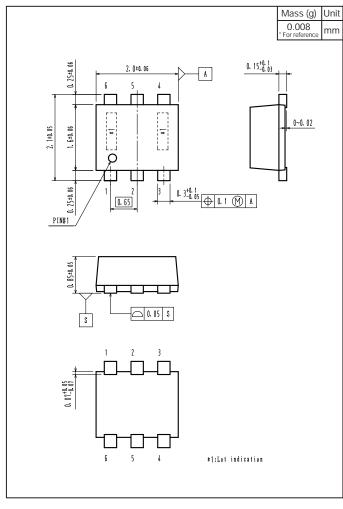
2. Taping configuration

2-1. Carrier tape size (unit:mm)

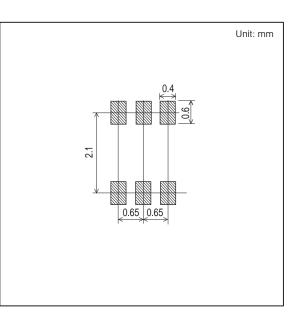


Those with pin 1 index on the feed hole side TL

Outline Drawing MCH6001-TL-E



Land Pattern Example



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